Listing of the Claims:

The following is a complete listing of all the claims in the application, with an indication of the status of each:

1. (Canceled)

2. (Currently amended) A method of producing a carbon nanotube, comprising: preparing a one dimensional carbon structure:

introducing a catalyst substance into said one dimensional carbon structure;

making said catalyst substance move in said one dimensional carbon structure: and

crystallizing a trail region of movement of said catalyst in said one dimensional carbon structure, wherein said step of crystallizing converts said trail region to a carbon nanotube. The method of producing a carbon nanotube according to claim 1, wherein said crystallizing said trail region is performed after said one dimensional carbon structure is fixed on a predetermined position of a substrate.

3-4. (Canceled)

5. (Currently amended) A method of producing a carbon nanotube, comprising:

preparing a one dimensional carbon structure. The method of producing a carbon nanotube according to claim 1, wherein said one dimensional carbon structure is formed by a vapor-phase deposition method of using a charged particle beam as an excitation source:

introducing a catalyst substance into said one dimensional carbon structure;

making said catalyst substance move in said one dimensional carbon structure; and

crystallizing a trail region of movement of said catalyst in said one dimensional carbon structure, wherein said step of crystallizing converts said trail region to a carbon nanotube. Docket: 09780001aa

6. (Currently amended) A method of <u>producing a carbon nanotube, comprising:</u>

<u>preparing a one dimensional carbon structure</u> The method of producing a carbon nanotube according to claim 1, wherein said one dimensional carbon structure is prepared by a vapor-phase deposition method of using an aromatic hydrocarbon compound as a precursor material;

introducing a catalyst substance into said one dimensional carbon structure:

making said catalyst substance move in said one dimensional carbon structure; and

crystallizing a trail region of movement of said catalyst in said one dimensional carbon structure, wherein said step of crystallizing converts said trail region to a carbon nanotube.

7. Currently amended) A method of <u>producing a carbon nanotube</u>, <u>comprising</u>: <u>preparing a one dimensional carbon structure</u> The method of producing a carbon nanotube according to claim 1, wherein said one dimensional carbon structure is a resist pattern:

introducing a catalyst substance into said one dimensional carbon structure;

making said catalyst substance move in said one dimensional carbon structure: and

crystallizing a trail region of movement of said catalyst in said one dimensional carbon structure, wherein said step of crystallizing converts said trail region to a carbon nanotube.

8-9. (Canceled)

 (Previously presented) A method of producing a carbon nanotube, comprising: preparing a substrate;

forming a one dimensional carbon structure at a position separated from a surface of the substrate;

preparing a carbon nanotube by making a catalyst substance move in the one dimensional carbon structure; and crystallizing a trail region of movement of said catalyst in said one dimensional carbon structure, wherein said step of crystallizing converts said trail region to said carbon nanotube.

- 11. (Previously presented) The method of producing a carbon nanotube according to claim 10, wherein said one dimensional carbon structure is heated when said catalyst substance is moved in the carbon structure.
- 12. (Previously presented) The method of producing a carbon nanotube according to claim 11, wherein at least part of said catalyst substance is liquefied by heating said one dimensional carbon structure.
- 13. (Previously presented) The method of producing a carbon nanotube according to claim 10, wherein said one dimensional carbon structure is formed by a vapor-phase deposition method of using a charged particle beam as an excitation source.
- 14. (Previously presented) The method of producing a carbon nanotube according to claim 10, wherein said one dimensional carbon structure is prepared by a vapor-phase deposition method of using an aromatic hydrocarbon compound as a precursor material.
- 15. (Previously presented) The method of producing a carbon nanotube according to claim 10, wherein said one dimensional carbon structure is a resist pattern.
- 16-23 (Canceled)
- 24. (Previously submitted) A method of producing a transistor, comprising forming a carbon nanotube structure by
 - preparing a substrate;

forming a one dimensional carbon structure at a position separated from a surface of said substrate;

preparing a carbon nanotube by making a catalyst substance move

in said one dimensional carbon structure; and crystallizing a trail region of movement of said catalyst in said one dimensional carbon structure, wherein said step of crystallizing converts said trail region to said carbon nanotube structure;

forming a source electrode and a drain electrode on both ends of said carbon nanotube structure, respectively; and

forming a gate electrode on said carbon nanotube structure.

25. (Previously submitted) A method of producing a wiring structure of carbon nanotube, comprising

forming a carbon nanotube by

preparing a substrate;

forming a one dimensional carbon structure at a position separated from a surface of said substrate;

preparing a carbon nanotube by making a catalyst substance move in said one dimensional carbon structure; and crystallizing a trail region of movement of said catalyst in said carbon structure, wherein said step of crystallizing converts said trail region to said carbon nanotube.